



HOM-Damper Development for the S-Band Linear Collider

Content

1) Theoretical work

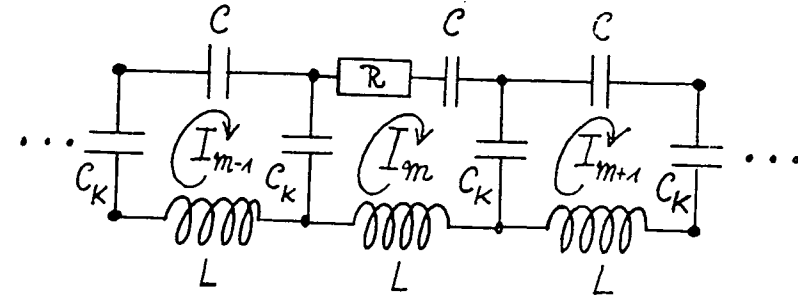
The effect of a single damper cell within a channel of undamped cells, calculated analytically using a simple equivalent circuit model

2) Measurements on a damped 12 cell constant impedance structure

The 12 cell structure is loaded by a single damper cell with well slots. The damping effect of three different slot widths was measured.

3) Conclusions

Circuit equations



Near-actively coupled circuits terminated by full end cells

$$\left(\Omega - \frac{K}{2}\right)I_1 - \frac{K}{2}I_2 = 0 \quad (\text{left end cell})$$

.....

$$\left(\Omega - K - i \frac{\omega}{\omega_0} \frac{1}{Q}\right)I_m - \frac{K}{2}(I_{m-1} + I_{m+1}) = 0$$

.....

$$\left(\Omega - \frac{K}{2}\right)I_N - \frac{K}{2}I_{N-1} = 0 \quad (\text{right end cell})$$

(Full end cells simulate electrical boundary conditions.)

$$\Omega = \left(\frac{\omega}{\omega_0}\right)^2 - 1, \quad \omega_0^2 = \frac{1}{LC}, \quad Q = \omega_0 \frac{L}{R}$$

$$\text{Bandwidth } K = 2 \frac{|\omega_r - \omega_0|}{\omega_r + \omega_0} \approx 2 \frac{C}{C_K}$$

From the equation of the damped all follows that

$$\operatorname{Re} \left(\frac{1}{i\omega C_K} (I_{m-1} I_m^* + I_{m+1} I_m^*) \right) = R I_m I_m^*$$

This is a statement regarding energy flow.

For all modes the dominant change in the field due to the presence of the damped turns out to be a phase shift in the argument of the field. We may then write:

$$\operatorname{Re} \left(\frac{1}{i\omega C_K} (A_m A_{m-1} e^{i\Delta\varphi} - A_m A_{m+1} e^{-i\Delta\varphi}) \right) = R A_m^2$$

A_{m-1} , A_m and A_{m+1} are the unperturbed amplitudes

In the case of full end cells with metallic boundary conditions we have simply:

$$A_m^{\varphi} = C_{\varphi} \cos\left(\frac{\varphi\pi}{N} \left(m - \frac{1}{2}\right)\right) \begin{cases} m = 1, 2, \dots, N \\ \varphi = 0, 1, \dots, N-1 \end{cases}$$

$$\frac{1}{Q} = K \sin(\Delta\varphi)$$

$Q \triangleq Q$ value of the damped cell

$K \triangleq$ bandwidth of the passband

$\Delta\varphi \triangleq$ phase shift due to the damped

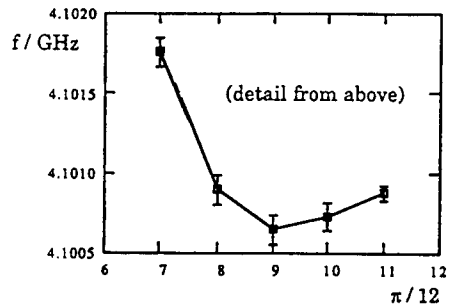
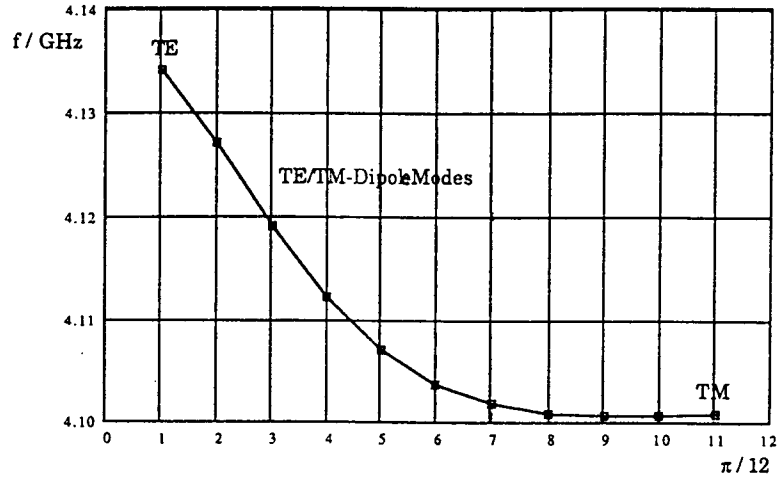
damping condition:

$\Delta\varphi$ has to be a real number

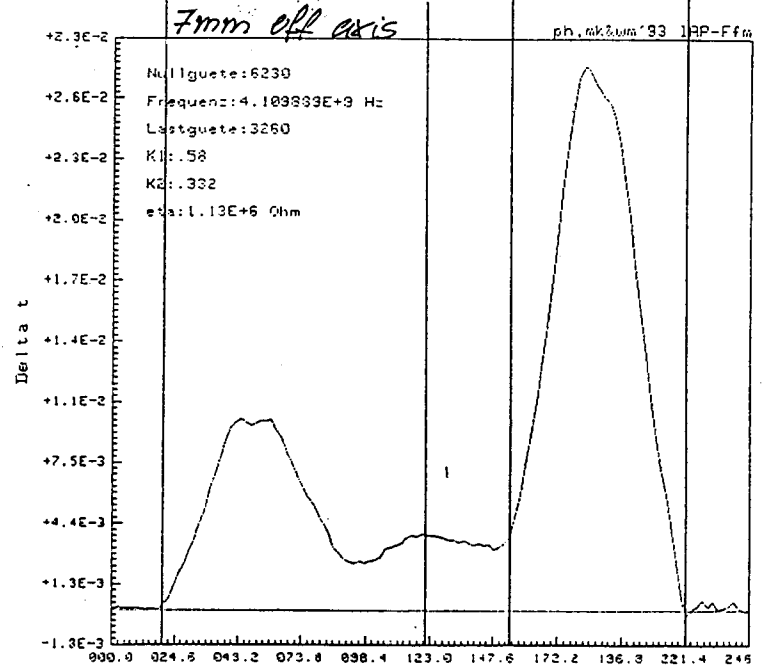
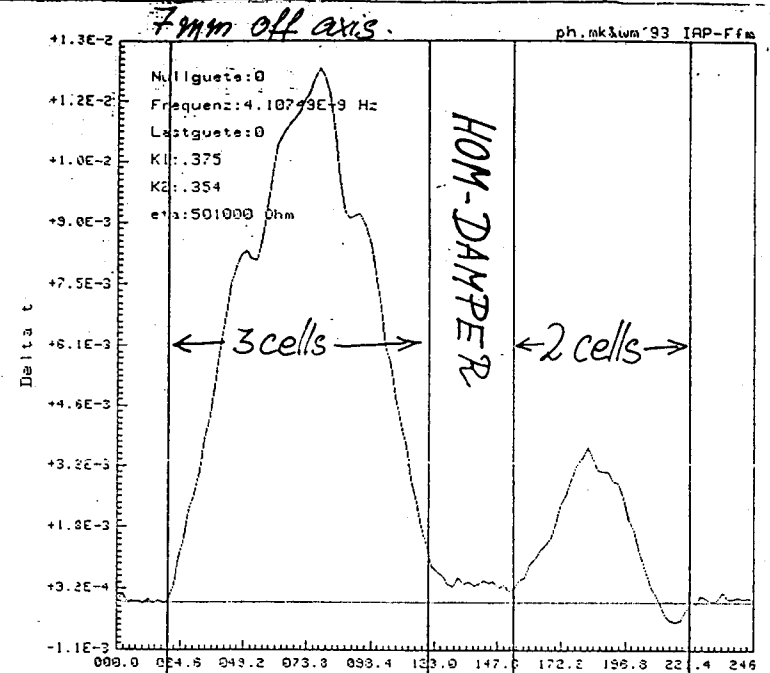
thus

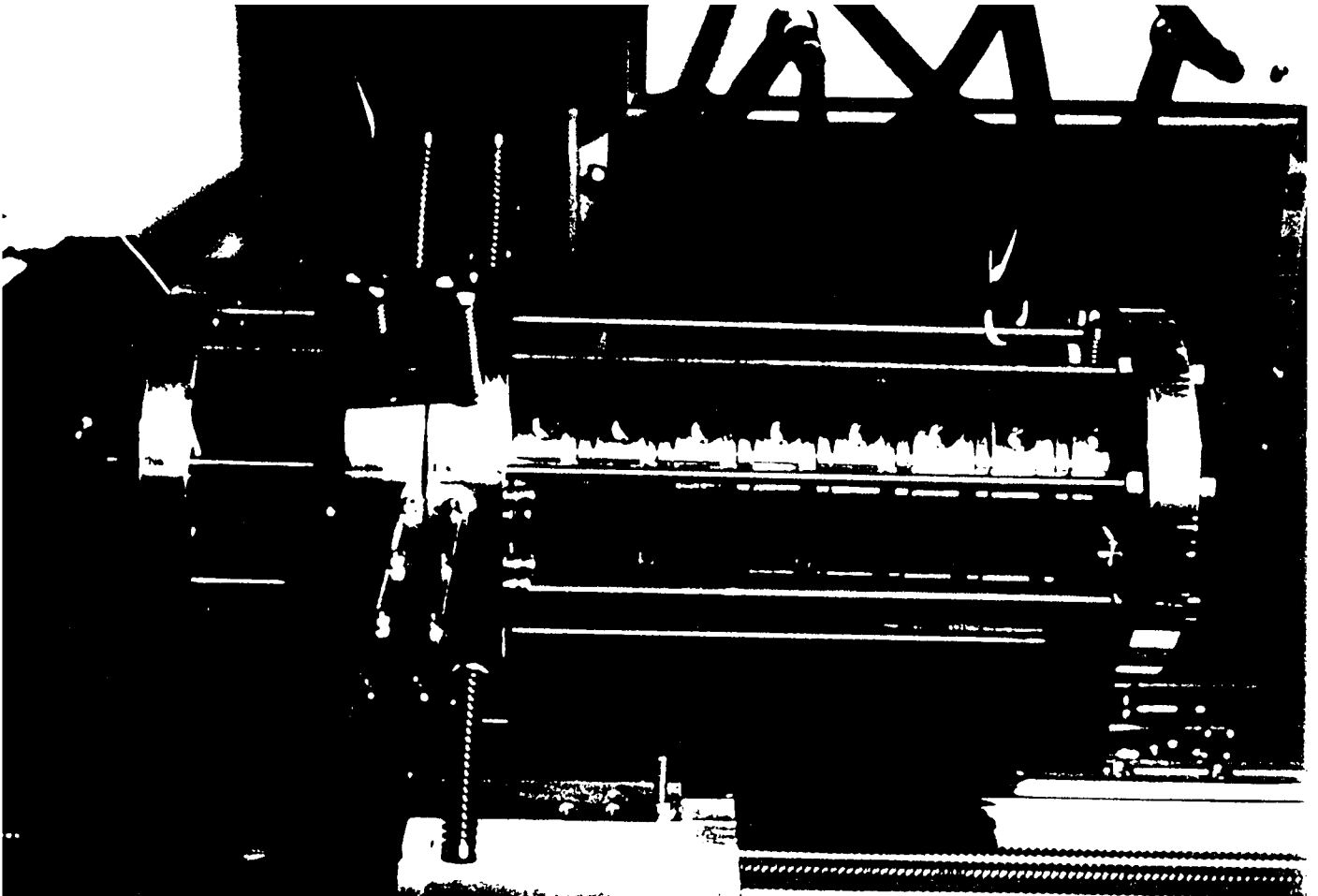
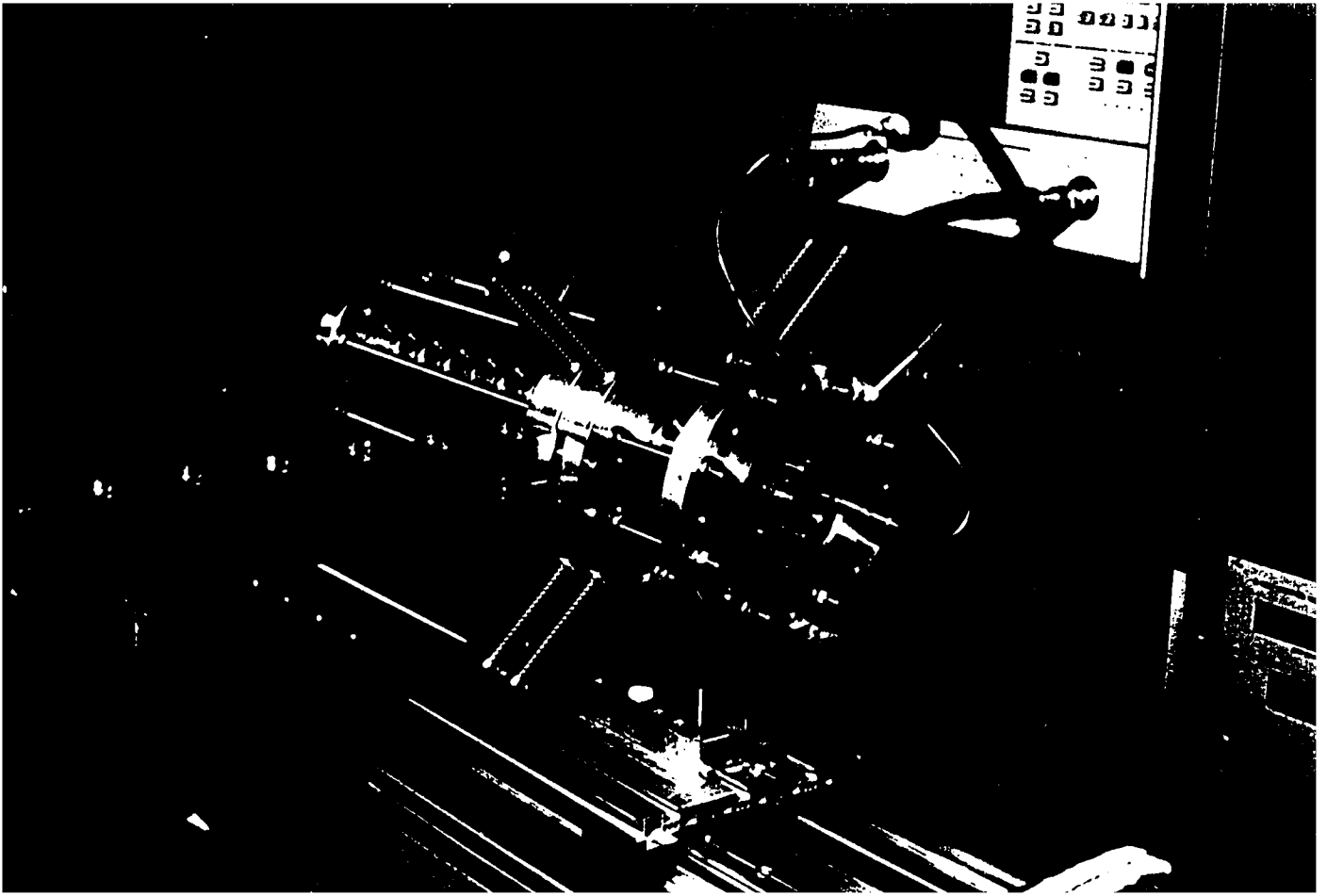
$$K Q = \frac{1}{\sin(\Delta\varphi)} \geq 1$$

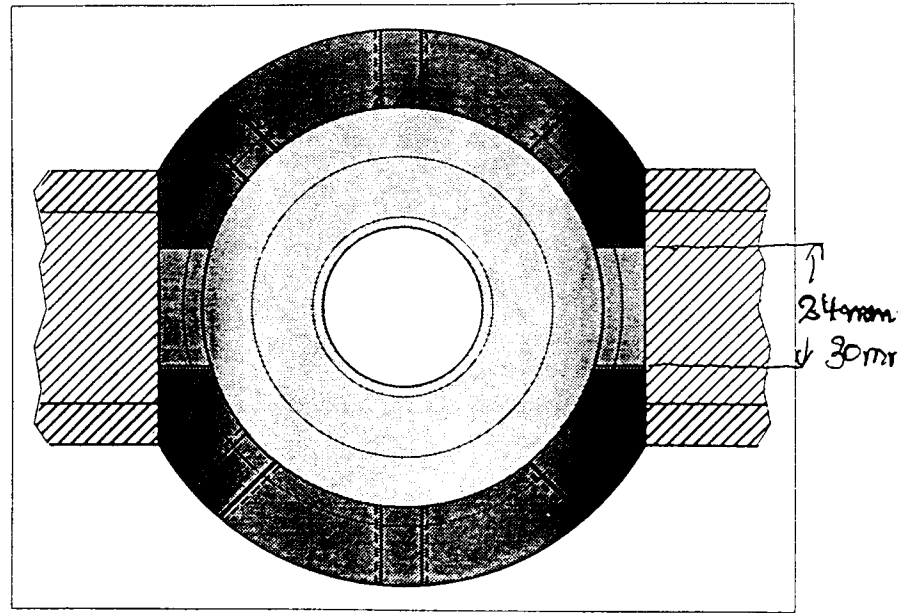
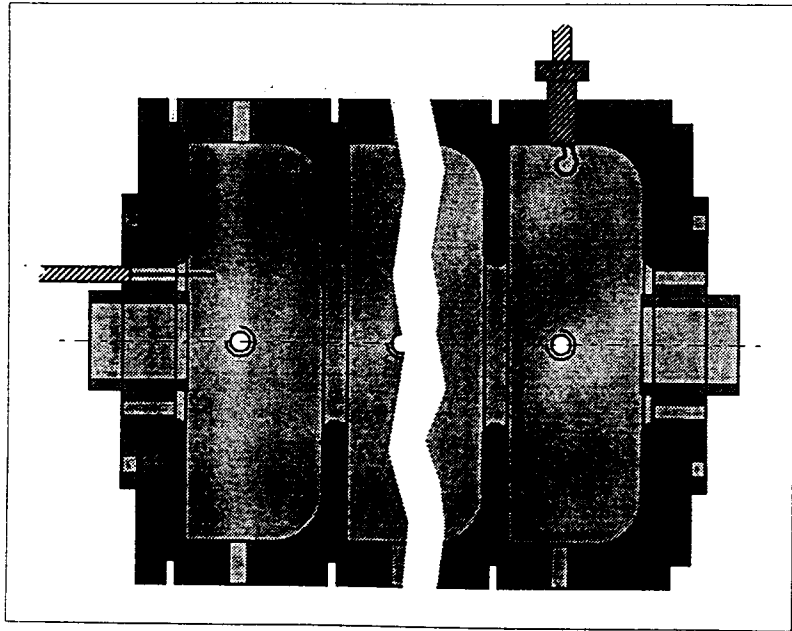
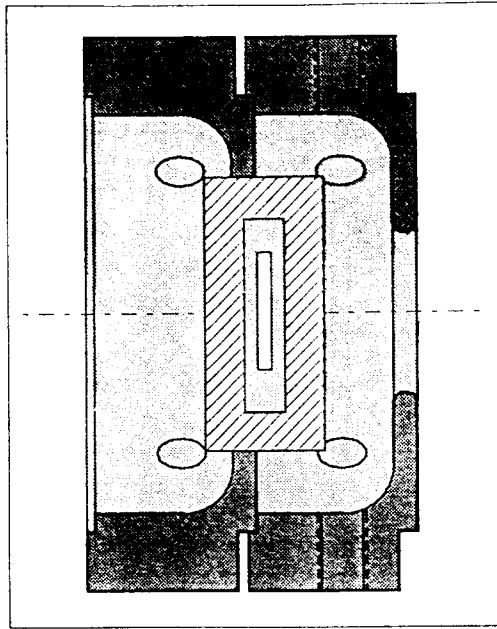
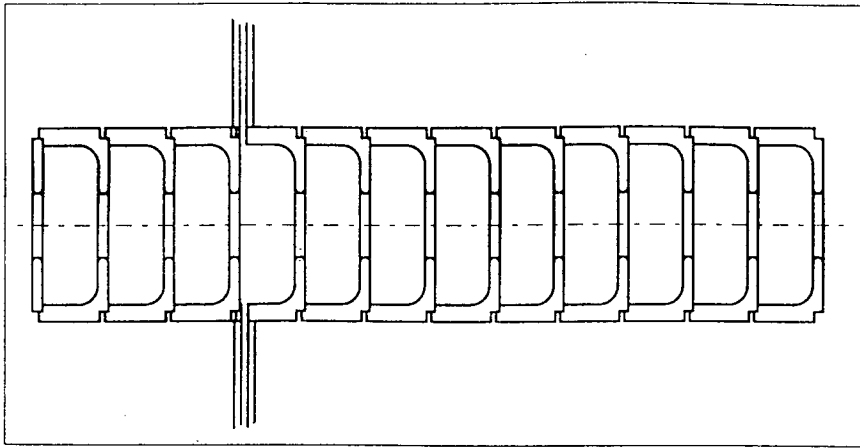
**Modes of the 12-Cell-DESY/THD-Structure
(calculated with MAFIA)**



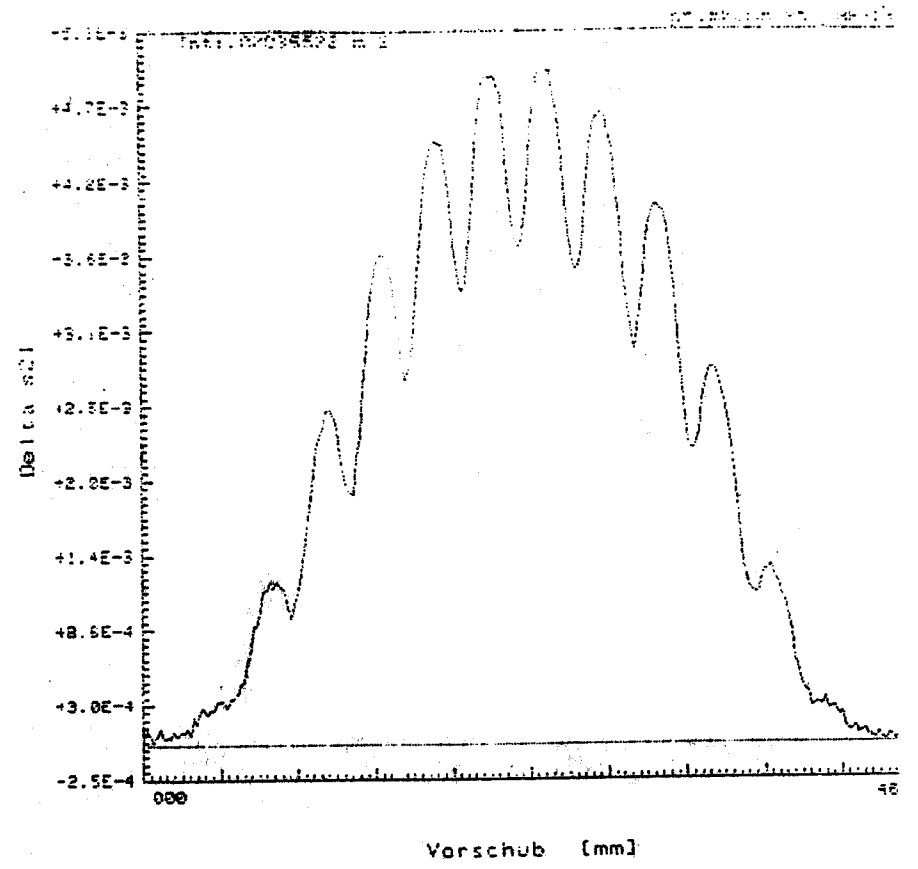
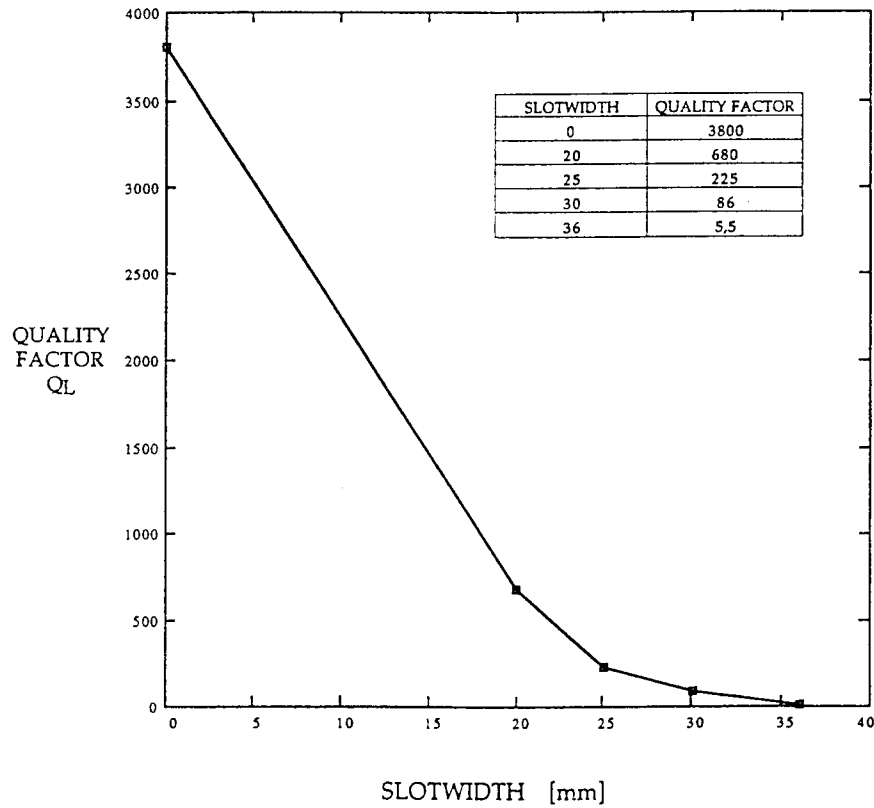
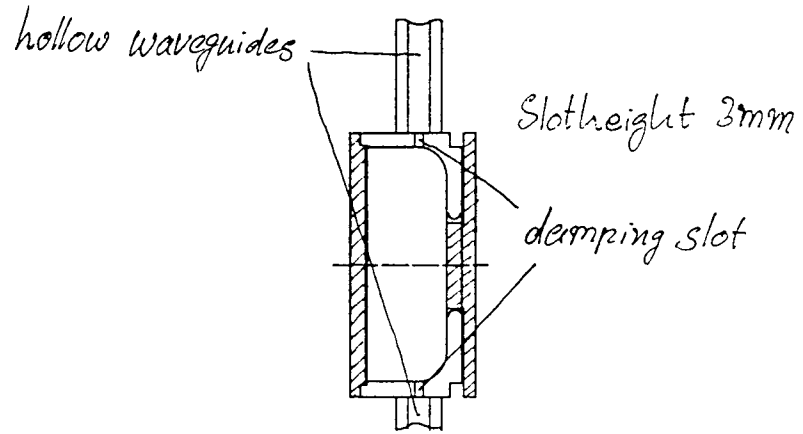
passband is extremely flat
 very low coupling between cells
 ~ 35 MHz bandwidth





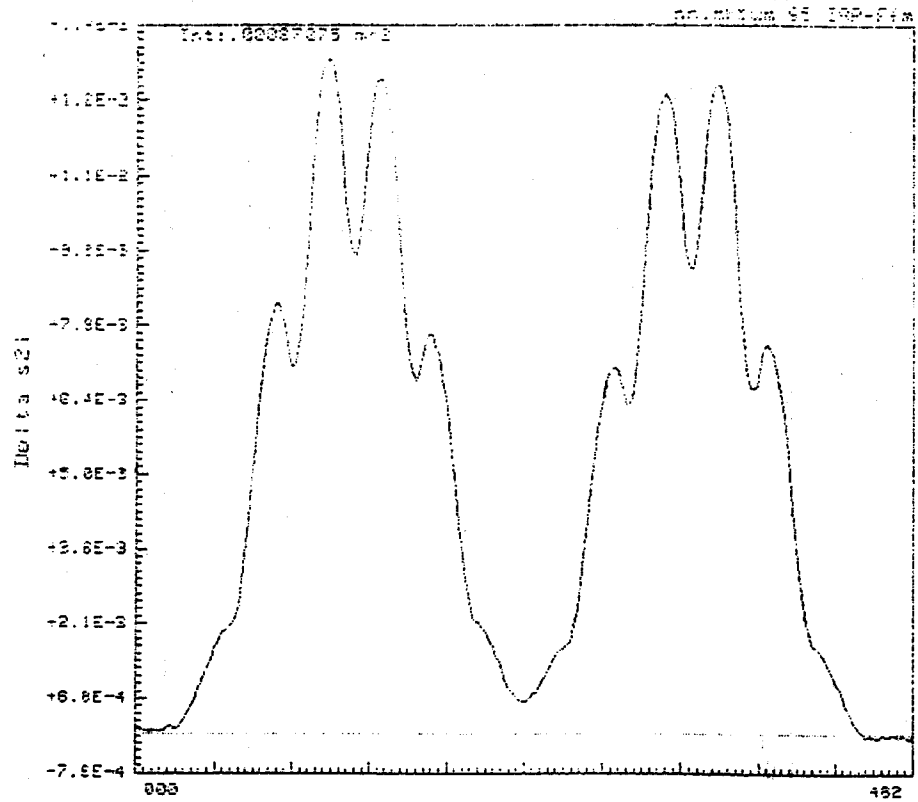


What slotwidth is needed ?



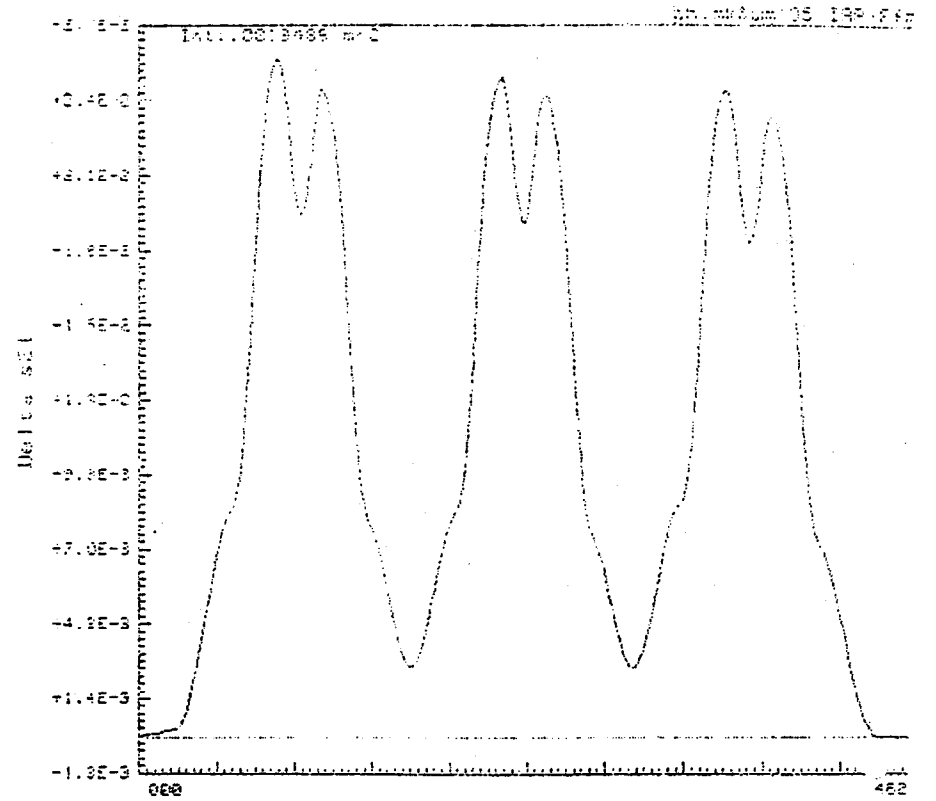
Messung: ATARI Paro Platten 3220 End
 anderer Platten

31.01.95



Vorschub [mm]

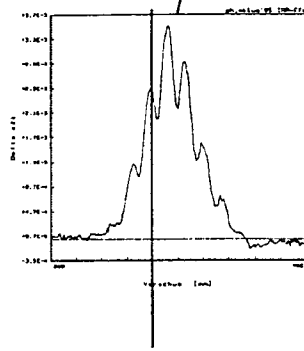
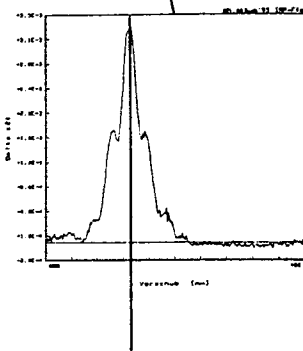
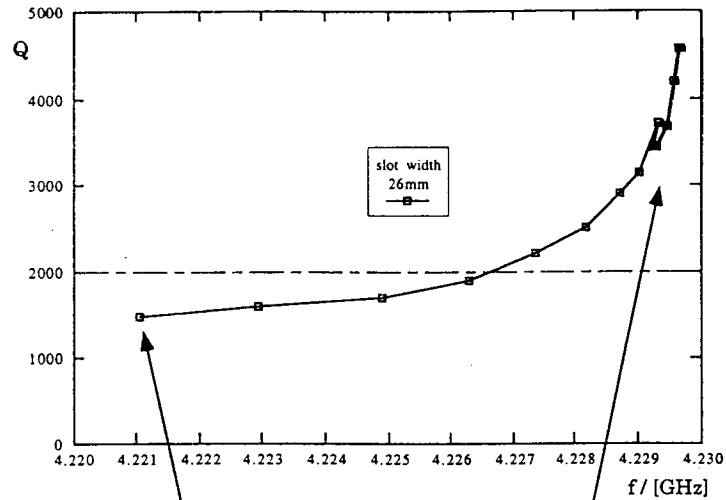
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Vorschub [mm]

The behaviour of the $TE/TM - \frac{11}{12}\pi$ -mode with respect to the tuning of the damper cell.

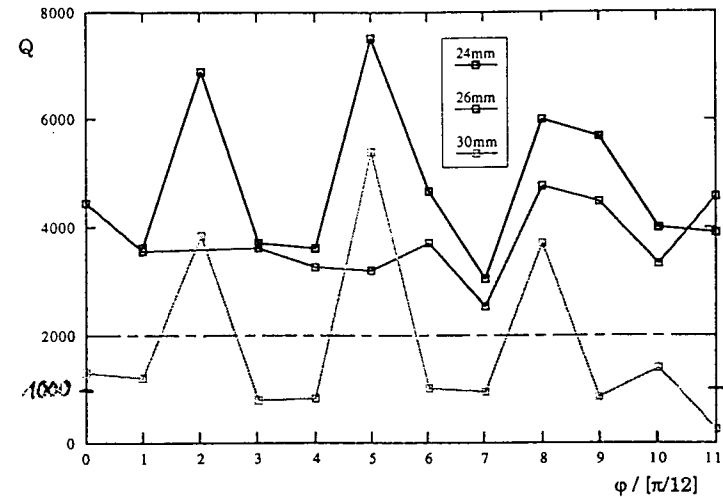
Q-values of the $TE/TM - 11\pi/12$ -dipole-mode



location of the damper cell

Results for different slotwidth

Q-values of the TE/TM -dipole-passband



Conclusion

- 1) Damping with one damper cell within a chain of undamped cells is a question of bandwidth.
- 2) Tuning of the damper cell with respect to the fundamental mode and the dipole modes is difficult
- 3) To increase the damping effect to a maximum we have to find the lowest possible single cell Q fulfilling the criterion